TOSHIBA PHOTOCOUPLER IRED & PHOTO-IC

TLP2116

- Plasma Display Panels (PDP)
- High-Speed Interfaces
- Factory Automation (FA)

The TOSHIBA TLP2116 dual photocoupler consists of a pair of an infrared emitting diodes optically coupled to integrated high gain and high-speed photodetectors.

- Inverter logic (totem-pole output)
- Package: SO8
- Guaranteed performance over temperature : -40 to 100°C
- Power supply voltage: 4.5 to 5.5 V
- Input thresholds current: IFHL = 5 mA (max)
- Propagation delay time (tpHL/tpLH): 75 ns (max)
- Switching speed: 15 MBd (typ.) (NRZ)
- Common mode transient immunity: ±10 kV/μs
- Isolation voltage: 2500 Vrms
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A

File No.E67349

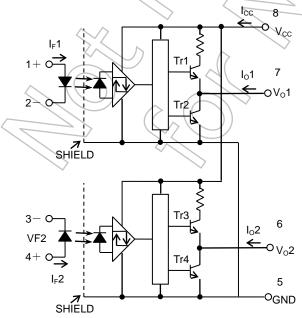
• VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed, Please designate the **Option(V4)**.

Truth Table

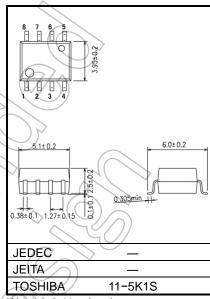
Input	LED1(2)	Tr1(3) Tr2(4)	Output 1(2)
Н	ON /	OFF	L (
L	OFF/	ON OFF	(H (V

Schematic



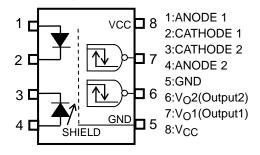
A bypass capacitor of 0.1 μF must be connected between pins 8 and 5.

Unit: mm



Weight: 0.11 g (typ.)

Pin Configuration (Top View)



Start of commercial production 2008-02

Absolute Maximum Ratings (Ta=25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	(Each Channel)	lF	20	mA
	Forward current derating $(Ta \ge 8)$	⊿I _F /⊿Ta	-0.5	mA/°C	
_	Peak transient forward current (E	ach Channel) (Note 1)	IFPT	1 <	Α
LED	Reverse voltage	(Each Channel)	V_{R}	5	V
	Input Power Dissipation	(Each Channel)	P_{D}	40	mW
	Input Power Dissipation Derating (Ta≥85°C)	ΔP _D /°C	-1.0	mW/°C	
	Output current	(Each Channel)	Ю	10	mA
ᄶ	Output voltage	(Each Channel)	Vo	6	V
CTOR	Supply voltage		Vcc	6	V
DETE	Output power dissipation Channel)	(Each	Po	40	mW
	Output Power Dissipation Derating (Ta	ı ≥ 85°C) (Each Channel)	△PO/°C	-1.0	mW/°C
Opera	ating temperature range	Topr	-40 to 100	°C	
Stora	ge temperature range	T _{stg}	-55 to 125	·c	
Lead	solder temperature	T _{sol}	260	°C	
Isolat	ion voltage (AC,60 s, R.H. ≤ 60 %,)	BVs	2500	Vrms	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Pulse width PW \leq 1 μ s, 300 pps.

Note 2: This device is regarded as a two terminal device: pins 1, 2, 3 and 4 are shorted together, as are pins 5, 6, 7 and 8.

Recommended Operating Conditions

Characte	Symbol	Min	Тур.	Max	Unit	
Input current, ON	I _{F(ON)}	8	1	18	mA	
Input voltage, OFF	(Each Channel)	VF(OFF)	0	ı	0.8	V
Supply voltage(*)	(Note 3)	Vcc	4.5	5.0	5.5	V
Operating temperature)) T _{opr}	-40	_	100	°C

^(*) This item denotes operating ranges, not meaning of recommended operating conditions.

Note 3: The detector of this product requires power supply voltage (VCC) of 4.5 V or higher for stable operation.

If the VCC is lower than this value, ICCH may increase, or output may be unstable.

Be sure to use the product after checking the supply current, and the operation of a power-on/-off.

Note: A ceramic capacitor $(0.1~\mu F)$ should be connected from pin 8 (VCC) to pin 5 (GND) to stabilize the operation of the high gain linear amplifier. Failure to provide the bypass may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.



Electrical Characteristics (Unless otherwise specified, Ta = -40 to 100°C, Vcc = 4.5 to 5.5V)

Characteristic		Symbol	Conditions	Min	Тур.	Max	Unit
Input forward voltage	(Each Channel)	VF	I _F = 10 mA, Ta = 25 °C	1.3	1.65	1.75	V
Temperature coefficient of forward voltage	(Each Channel)	⊿V _{F/} ⊿Ta	I _F = 10 mA	-	-2.0	1	mV/°C
Input reverse current	(Each Channel)	IR	V _R = 5 V, Ta = 25 °C			10	μА
Input capacitance	(Each Channel)	Ст	V = 0 V, f = 1 MHz, Ta = 25 °C		1 45	_	pF
Logic low output voltage	(Each Channel)	VoL	I _{OL} = 1.6 mA, I _F = 12 mA, V _{CC} = 5 V		<u> </u>	0.4	V
Logic high output voltage	(Each Channel)	Vон	$I_{OH} = -0.02 \text{ mA}, V_F = 1.05 \text{ V}$ $V_{CC} = 5 \text{ V}$	4.0	-		V
Logic low supply current		ICCL	IF = 12 mA	→ –	-<	10.0	mA
Logic high supply current		Іссн	V _F = 0 V (Note 3)	$\overline{\Diamond}$	\bigcirc	10.0	mA
Input current logic low output	(Each Channel)	IFHL	I _O =1.6 mA, V _O < 0.4 V	-		5	mA
Input voltage logic high output	(Each Channel)	VFLH	$I_O = -0.02 \text{ mA}, V_O > 4.0 \text{ V}$	0.8	\bigcirc	_	V

^{*}All typical values are at Ta=25°C, V_{CC}=5 V unless otherwise specified

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions		Min	Тур.	Max	Unit
Capacitance input to output	Cs	V _S = 0 V, f = 1 MHz	(Note 2)	_	0.8	_	pF
Isolation resistance	7/\Rs	R.H. ≤ 60 %, V _S = 500 V	(Note 2)	1×10 ¹²	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC, 60-s	(Note 2)	2500	_	_	Vrms

Switching Characteristics

(Unless otherwise specified, Ta = -40 to 100°C, Vcc = 4.5 to 5.5V)(Each Channel)

Characteristic	Symbol	Test Circuit	Conditions		Min	Тур.	Max	Unit
Propagation delay time to logic low output	tрНL	_	I _F = 0→12 mA	R _{IN} = 100 Ω	1 <	_	75	ns
Propagation delay time to logic high output	t _{pLH}	1	IF = 12→0 mA	$C_L = 15 pF$ (Note 5)	-	1	75	ns
Propagation delay time to logic low output	t _{pHL}		$V_{IN} = 0 \rightarrow 5 V$ $(I_F = 0 \rightarrow 8 \text{ mA})$	RIN = 430 Ω CIN = 27 pF			75	ns
Propagation delay time to logic high output	tpLH	2	$V_{IN} = 5 \rightarrow 0 V$ $(I_F = 8 \rightarrow 0 \text{ mA})$	C _L = 15 pF (Note 5)))	_	75	ns
Switching time dispersion between ON and OFF	tpHL - tpLH		$I_F = 12 \text{ mA}, R_{IN} = C_L = 15 \text{ pF}$ (Note)	-	30	ns
Output fall time (90 - 10%)	t _f	1	IF = 0→12 mA	RIN =100 Ω	_	15		ns
Output rise time (10 - 90%)	t _r		I _F = 12→0 mA	C _L =15 pF (Note 5)	\Diamond	(15)/	\ \	ns
Common mode transient immunity at high level output	СМн		$VC_{M} = 1000 \text{ Vp-p}$ $V_{O} \text{ (min)} = 4 \text{ V},$		10000		//_	V/μs
Common mode transient immunity at low level output	CML	3	$VC_{M} = 1000 \text{ Vp-p}$ $V_{O} \text{ (max)} = 0.4 \text{ V}$		-10000)) –	_	V/μs

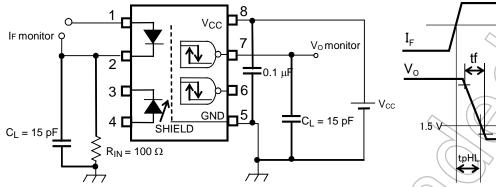
^{*}All typical values are at Ta = 25 $^{\circ}$ C

Note 5: CL is approximately 15 pF which includes probe and Jig/stray wiring capacitance.



Test Circuit 1: Switching Time Test Circuit

 $I_F=12 \text{ mA (P.G)} \\ (f=5 \text{ MHz, duty}=50\%, \\ less than t_r=t_f=5 \text{ ns)}$



I_F

V_O

tf
V_O

VOH

1.5

VOL

tpHL

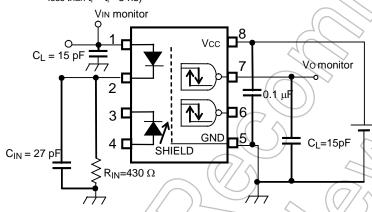
tpLH

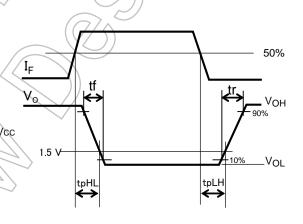
tpLH

 C_L is capacitance of the probe and JIG. (P.G): Pulse Generator

Test Circuit 2: Switching Time Test Circuit

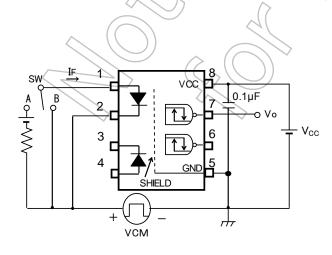
VIN=5V (P.G) (f=5 MHz, duty=50%, less than $t_r = t_f = 5$ ns)

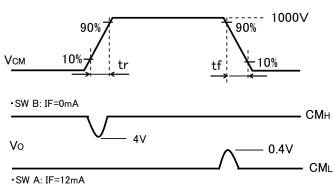




C_L is capacitance of the probe and JIG. (P.G): Pulse Generator

Test Circuit 3: Common-Mode Transient Immunity Test Circuit





$$CMH = \frac{800(V)}{tr(\mu s)} \qquad CML = -\frac{800(V)}{tf(\mu s)}$$

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
 EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
 MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
 ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
 limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical
 equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to
 control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE
 PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
 TOSHIBA sales representative or contact us via our website.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
 applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
 FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
 WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
 LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
 LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
 SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
 FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
 limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
 technology products (mass destruction weapons). Product and related software and technology may be controlled under the
 applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
 U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
 except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of
 Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled
 substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
 OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION

https://toshiba.semicon-storage.com/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for High Speed Optocouplers category:

Click to view products by Toshiba manufacturer:

Other Similar products are found below:

TLP558(F) JAN4N24 610737H HCPL2630M HCPL2731SM HCPL2630SM PS9817A-1-F3-AX EL816S2(C)(TU)-F TLP281-4

TLP290(V4GBTP,SE(T PS9121-F3-AX PS9123-F3-AX TLP5774H(TP4,E TLP5771H(TP,E HCPL2531S HCPL2631SD HCPL-4661-500E

TLP118(TPL,E) TLP521-2XGB TLP621-2XGB 4N46-300E JANTXV4N24U SFH6318T 6N135-300E TIL198 TLP2309(TPL,E)

TLP2355(TPL,E TLP2391(E(T TLP521-4GR TLP521-4XGB TLP621-4X TLP621XSM IS281-4GB IS2805-4 IS181GR ICPL2631

ICPL2630 ICPL2531 ICPL2601 TLP714(F) TLP754(F) FOD260LSDV ACPL-M21L-500E ACPL-064L-500E PS2501-1XSM PS2505-1

PS2913-1-F3-AX PS9821-2-F3-AX FOD0721R2 FODM8061R2V